

# IR-Lumineszenzdiode (850 nm) mit hoher Ausgangsleistung

High Power Infrared Emitter (850 nm)

Lead (Pb) Free Product - RoHS Compliant

SFH 4550



## Wesentliche Merkmale

- Infrarot LED mit hoher Ausgangsleistung
- Enger Abstrahlwinkel  $\pm 3^\circ$
- Sehr hohe Strahlstärke
- Kurze Schaltzeiten
- UL Version erhältlich

## Anwendungen

- Infrarotbeleuchtung für Kameras
- Sensorik
- Datenübertragung
- Rauchmelder

## Sicherheitshinweise

Je nach Betriebsart emittieren diese Bauteile hochkonzentrierte, nicht sichtbare Infrarot-Strahlung, die gefährlich für das menschliche Auge sein kann. Produkte, die diese Bauteile enthalten, müssen gemäß den Sicherheitsrichtlinien der IEC-Normen 60825-1 und 62471 behandelt werden.

## Features

- High Power Infrared LED
- Narrow emission angle  $\pm 3^\circ$
- Very high radiant intensity
- Short switching times
- UL version available

## Applications

- Infrared Illumination for cameras
- Sensor technology
- Data transmission
- Smoke detectors

## Safety Advices

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

Type Type	Bestellnummer Ordering Code	Strahlstärkegruppierung <sup>1)</sup> ( $I_F = 100 \text{ mA}$ , $t_p = 20 \text{ ms}$ ) Radiant Intensity Grouping <sup>1)</sup> $I_e$ (mW/sr)
SFH 4550	Q65110A1772	$\geq 400$ (typ. 700)

<sup>1)</sup> gemessen bei einem Raumwinkel  $\Omega = 0.001 \text{ sr}$  / measured at a solid angle of  $\Omega = 0.001 \text{ sr}$

**Grenzwerte ( $T_A = 25^\circ\text{C}$ )****Maximum Ratings**

<b>Bezeichnung Parameter</b>	<b>Symbol Symbol</b>	<b>Wert Value</b>	<b>Einheit Unit</b>
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{\text{op}}, T_{\text{stg}}$	- 40 ... + 100	°C
Sperrspannung Reverse voltage	$V_R$	5	V
Vorwärtsgleichstrom Forward current	$I_F$	100	mA
Stoßstrom, $t_p = 10 \mu\text{s}, D = 0$ Surge current	$I_{\text{FSM}}$	1.5	A
Verlustleistung Power dissipation	$P_{\text{tot}}$	180	mW
Wärmewiderstand Sperrsicht - Umgebung bei Montage auf FR4 Platine, Padgröße je 16 mm <sup>2</sup> Thermal resistance junction - ambient mounted on PC-board (FR4), padsize 16 mm <sup>2</sup> each	$R_{\text{thJA}}$	450	K/W

**Kennwerte ( $T_A = 25^\circ\text{C}$ )****Characteristics**

<b>Bezeichnung Parameter</b>	<b>Symbol Symbol</b>	<b>Wert Value</b>	<b>Einheit Unit</b>
Wellenlänge der Strahlung Wavelength at peak emission $I_F = 100 \text{ mA}$	$\lambda_{\text{peak}}$	860	nm
Centroid-Wellenlänge der Strahlung Centroid wavelength $I_F = 100 \text{ mA}$	$\lambda_{\text{centroid}}$	850	nm
Spektrale Bandbreite bei 50% von $I_{\text{max}}$ Spectral bandwidth at 50% of $I_{\text{max}}$ $I_F = 100 \text{ mA}$	$\Delta\lambda$	42	nm
Abstrahlwinkel Half angle	$\phi$	$\pm 3$	Grad deg.
Aktive Chipfläche Active chip area	$A$	0.09	mm <sup>2</sup>
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B$ $L \times W$	$0.3 \times 0.3$	mm <sup>2</sup>

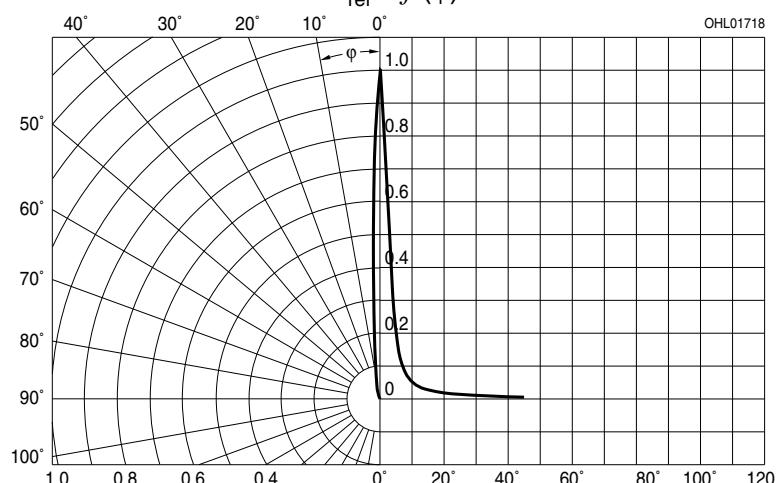
**Kennwerte ( $T_A = 25^\circ\text{C}$ )****Characteristics (cont'd)**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Schaltzeiten, $I_e$ von 10% auf 90% und von 90% auf 10%, bei $I_F = 100 \text{ mA}$ , $R_L = 50 \Omega$ Switching times, $I_e$ from 10% to 90% and from 90% to 10%, $I_F = 100 \text{ mA}$ , $R_L = 50 \Omega$	$t_r, t_f$	12	ns
Durchlassspannung Forward voltage $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	$V_F$ $V_F$	1.5 (< 1.8) 2.4 (< 3.0)	V V
Sperrstrom Reverse current	$I_R$	not designed for reverse operation	$\mu\text{A}$
Gesamtstrahlungsfluss Total radiant flux $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$\Phi_e \text{ typ}$	50	mW
Temperaturkoeffizient von $I_e$ bzw. $\Phi_e$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $I_e$ or $\Phi_e$ , $I_F = 100 \text{ mA}$	$TC_I$	- 0.5	%/K
Temperaturkoeffizient von $V_F$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $V_F$ , $I_F = 100 \text{ mA}$	$TC_V$	- 0.7	mV/K
Temperaturkoeffizient von $\lambda$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $\lambda$ , $I_F = 100 \text{ mA}$	$TC_\lambda$	+ 0.3	nm/K

**Strahlstärke  $I_e$  in Achsrichtung<sup>1)</sup>**gemessen bei einem Raumwinkel  $\Omega = 0.001 \text{ sr}$ **Radiant Intensity  $I_e$  in Axial Direction**at a solid angle of  $\Omega = 0.001 \text{ sr}$ 

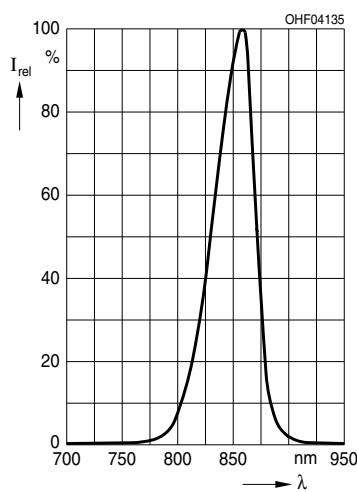
Bezeichnung Parameter	Symbol	Werte Values			Einheit Unit
		SFH 4550-DW	SFH 4550-EW	SFH 4550-FW	
Strahlstärke Radiant intensity $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$I_e$ min $I_e$ max	400 800	630 1250	1000 2000	mW/sr mW/sr
Strahlstärke Radiant intensity $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	$I_e$ typ	5000	7000	9000	mW/sr

<sup>1)</sup> Nur eine Gruppe in einer Verpackungseinheit (Streuung kleiner 2:1) /  
Only one group in one packing unit (variation lower 2:1)

**Abstrahlcharakteristik****Radiation Characteristics  $I_{\text{rel}} = f(\phi)$** 

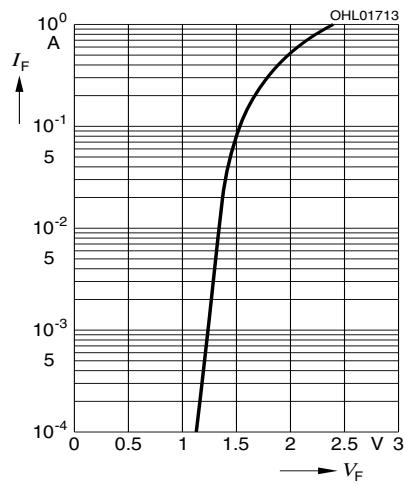
**Relative Spectral Emission**

$$I_{\text{rel}} = f(\lambda)$$



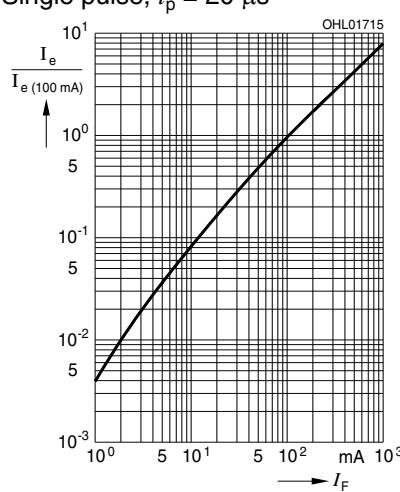
**Forward Current  $I_F = f(V_F)$**

Single pulse,  $t_p = 20 \mu\text{s}$



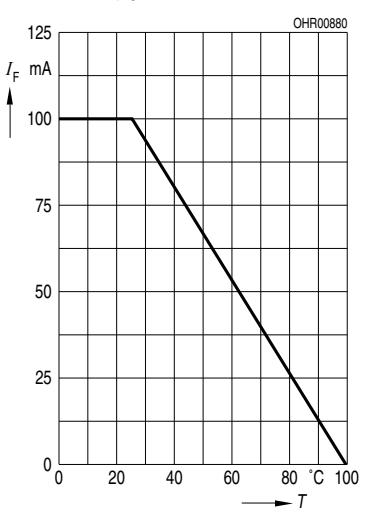
**Radiant Intensity  $\frac{I_e}{I_e(100 \text{ mA})} = f(I_F)$**

Single pulse,  $t_p = 20 \mu\text{s}$



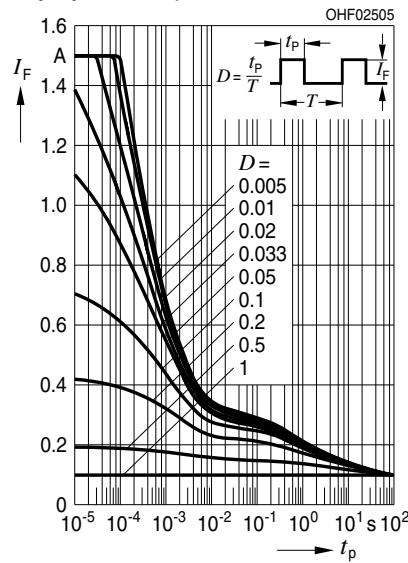
**Max. Permissible Forward Current**

$$I_F = f(T_A), R_{\text{thJA}} = 450 \text{ K/W}$$

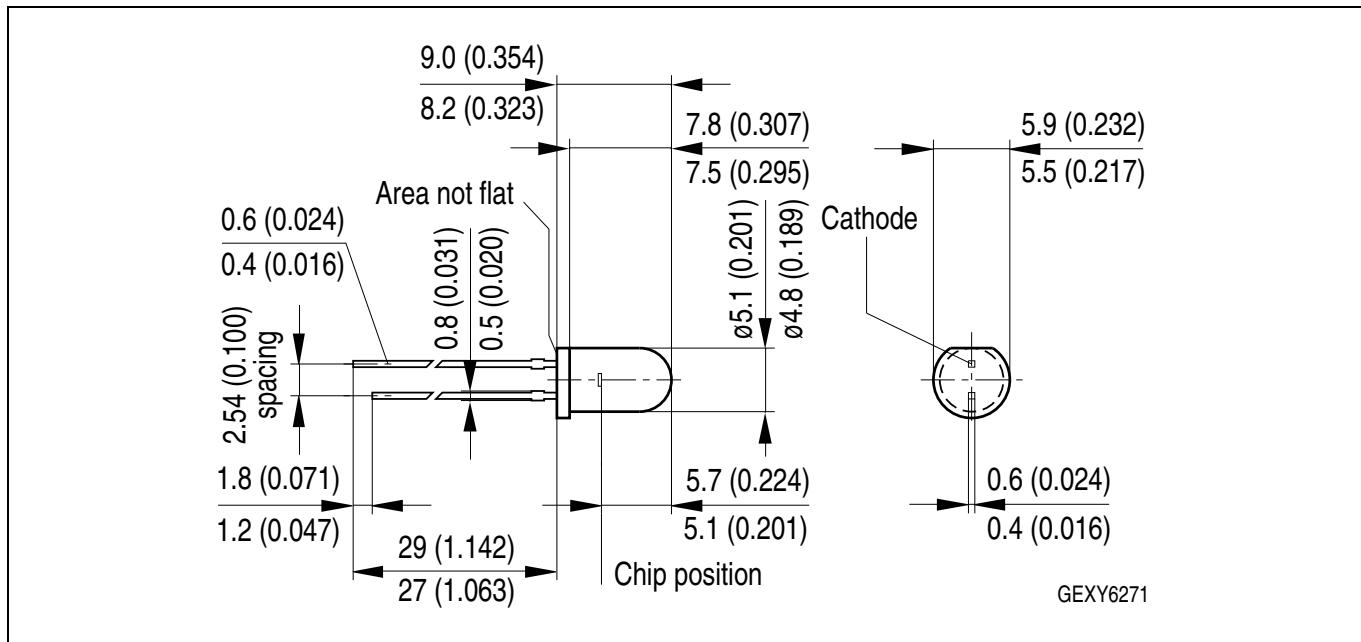


**Permissible Pulse Handling Capability**

$$I_F = f(\tau), T_A = 25^{\circ}\text{C}, \text{duty cycle } D = \text{parameter}$$



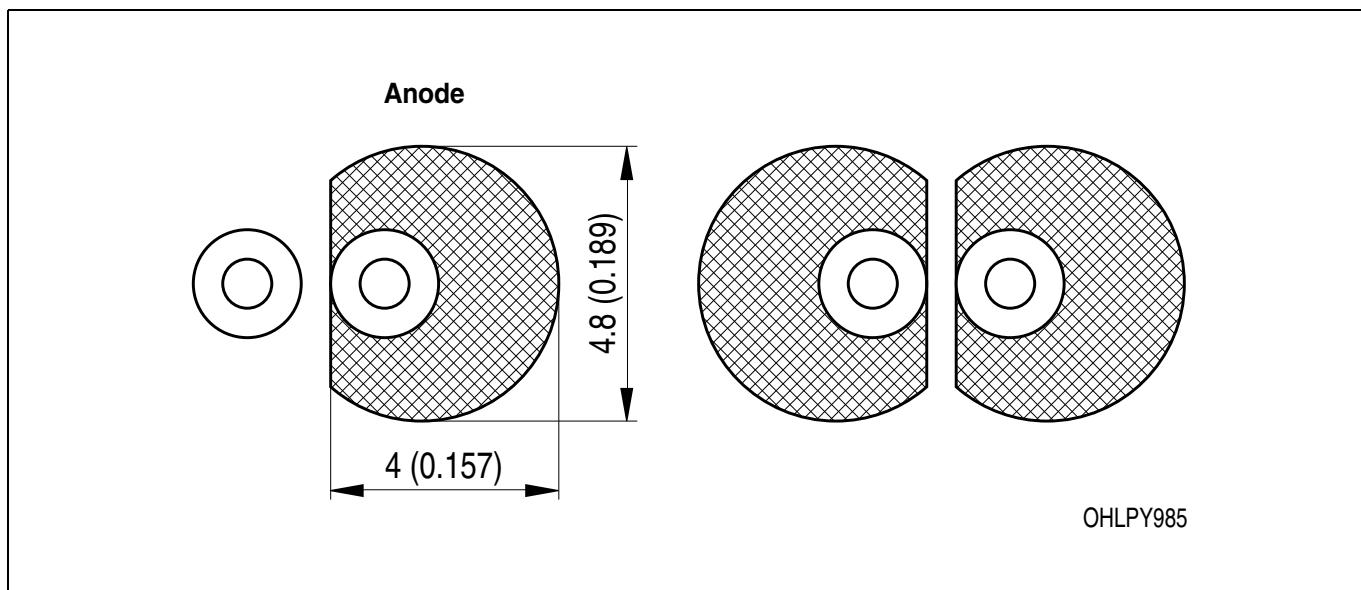
**Maßzeichnung**  
**Package Outlines**



Maße in mm (inch) / Dimensions in mm (inch).

**Empfohlenes Lötpaddesign**  
**Recommended Solder Pad Design**

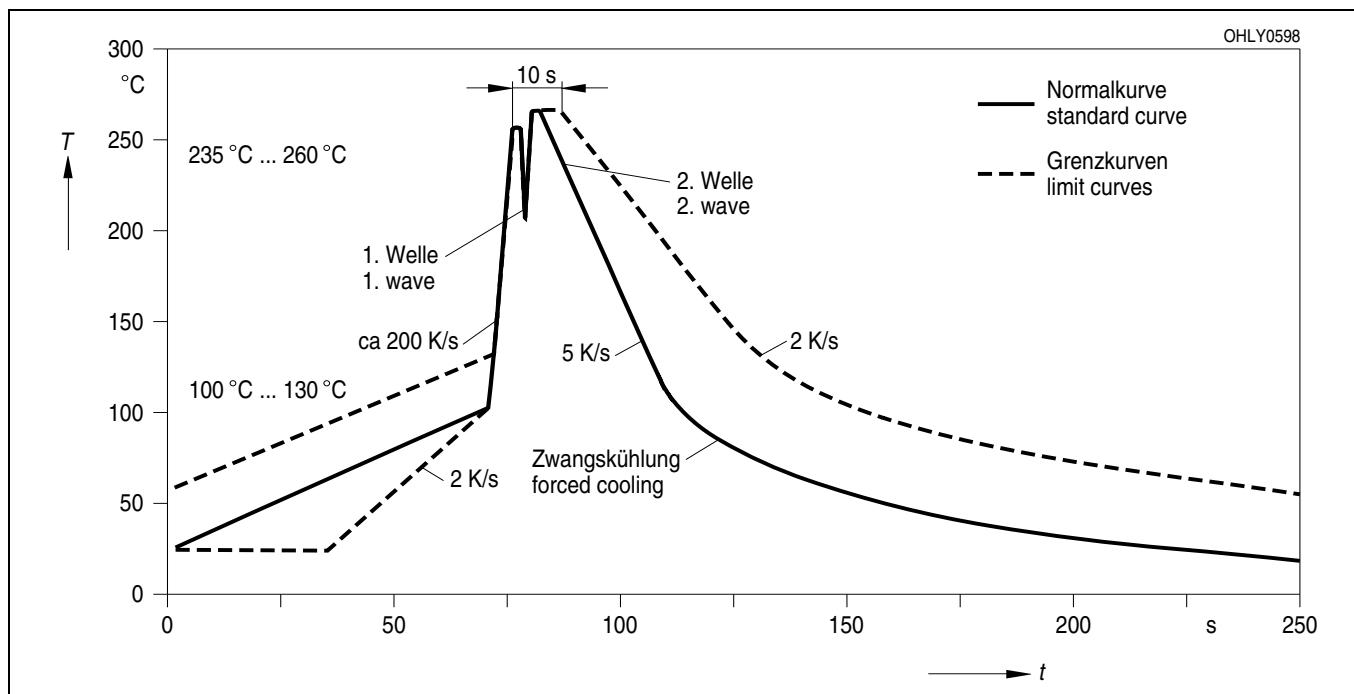
Wellenlöten TTW  
TTW Soldering



Maße in mm (inch) / Dimensions in mm (inch).

**Lötbedingungen**  
**Soldering Conditions**  
**Wellenlöten (TTW)**  
**TTW Soldering**

(nach CECC 00802)  
 (acc. to CECC 00802)



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